

TOSHIBA Field Effect Transistor Silicon N-Channel MOS Type (π -MOSVI)

2SK3903

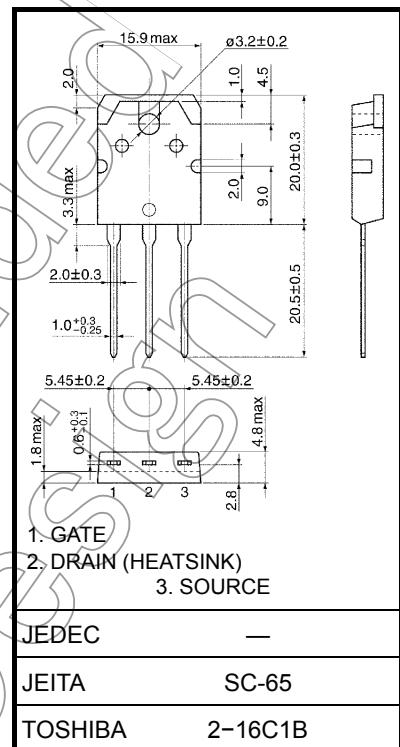
Switching Regulator Applications

Unit: mm

- Low drain-source ON resistance: $R_{DS(ON)} = 0.32 \Omega$ (typ.)
- High forward transfer admittance: $|Y_{fs}| = 7.5 \text{ S}$ (typ.)
- Low leakage current: $I_{DSS} = 100 \mu\text{A}$ (max) ($V_{DS} = 600 \text{ V}$)
- Enhancement model: $V_{th} = 2.0$ to 4.0 V ($V_{DS} = 10 \text{ V}$, $I_D = 1 \text{ mA}$)

Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$)

Characteristic	Symbol	Rating	Unit
Drain-source voltage	V_{DSS}	600	V
Drain-gate voltage ($R_{GS} = 20 \text{ k}\Omega$)	V_{DGR}	600	V
Gate-source voltage	V_{GSS}	± 30	V
Drain current	DC (Note 1)	I_D	A
	Pulse (Note 1)	I_{DP}	
Drain power dissipation ($T_c = 25^\circ\text{C}$)	P_D	150	W
Single pulse avalanche energy (Note 2)	E_{AS}	806	mJ
Avalanche current	I_{AR}	14	A
Repetitive avalanche energy (Note 3)	E_{AR}	15	mJ
Channel temperature	T_{ch}	150	$^\circ\text{C}$
Storage temperature range	T_{stg}	-55 to 150	$^\circ\text{C}$



Weight: 4.6 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc.).

Thermal Characteristics

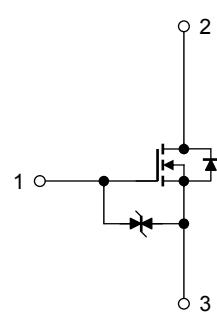
Characteristic	Symbol	Max	Unit
Thermal resistance, channel to case	$R_{th}(\text{ch-c})$	0.833	$^\circ\text{C/W}$
Thermal resistance, channel to ambient	$R_{th}(\text{ch-a})$	50	$^\circ\text{C/W}$

Note 1: Ensure that the channel temperature does not exceed 150°C during use of the device.

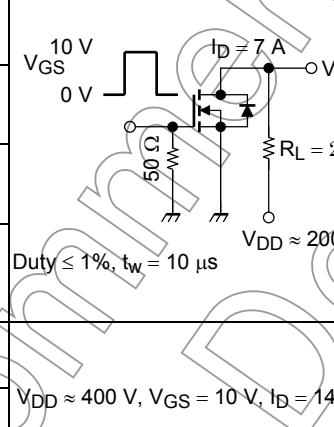
Note 2: $V_{DD} = 90 \text{ V}$, $T_{ch} = 25^\circ\text{C}$, $L = 7.2 \text{ mH}$, $R_G = 25 \Omega$, $I_{AR} = 14 \text{ A}$

Note 3: Repetitive rating: pulse width limited by max junction temperature

This transistor is an electrostatic-sensitive device. Handle with care.



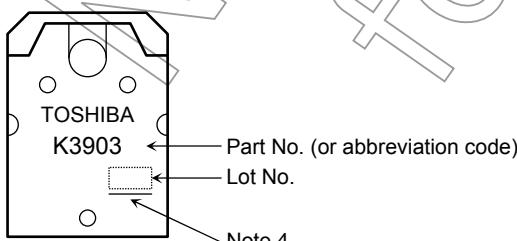
Electrical Characteristics ($T_a = 25^\circ\text{C}$)

Characteristic	Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current	I_{GSS}	$V_{GS} = \pm 25\text{ V}$, $V_{DS} = 0\text{ V}$	—	—	± 10	μA
Gate-source breakdown voltage	$V_{(\text{BR})\text{GSS}}$	$I_G = \pm 10\text{ }\mu\text{A}$, $V_{DS} = 0\text{ V}$	± 30	—	—	V
Drain cut-off current	I_{DSS}	$V_{DS} = 600\text{ V}$, $V_{GS} = 0\text{ V}$	—	—	100	μA
Drain-source breakdown voltage	$V_{(\text{BR})\text{DSS}}$	$I_D = 10\text{ mA}$, $V_{GS} = 0\text{ V}$	600	—	—	V
Gate threshold voltage	V_{th}	$V_{DS} = 10\text{ V}$, $I_D = 1\text{ mA}$	2.0	—	4.0	V
Drain-source on resistance	$R_{DS}\text{ (ON)}$	$V_{GS} = 10\text{ V}$, $I_D = 7\text{ A}$	—	0.32	0.44	Ω
Forward transfer admittance	$ Y_{fs} $	$V_{DS} = 10\text{ V}$, $I_D = 7\text{ A}$	2.1	7.5	—	S
Input capacitance	C_{iss}	$V_{DS} = 25\text{ V}$, $V_{GS} = 0\text{ V}$, $f = 1\text{ MHz}$	—	3100	—	pF
Reverse transfer capacitance	C_{rss}		—	20	—	
Output capacitance	C_{oss}		—	270	—	
Switching time	Rise time	t_r		—	70	—
	Turn-on time	t_{on}		—	130	—
	Fall time	t_f		—	70	—
	Turn-off time	t_{off}		—	280	—
Total gate charge (gate-source plus gate-drain)	Q_g	$V_{DD} \approx 400\text{ V}$, $V_{GS} = 10\text{ V}$, $I_D = 14\text{ A}$	—	62	—	nC
Gate-source charge	Q_{gs}		—	40	—	
Gate-drain ("Miller") charge	Q_{gd}		—	22	—	

Source-Drain Ratings and Characteristics ($T_a = 25^\circ\text{C}$)

Characteristic	Symbol	Test Condition	Min	Typ.	Max	Unit
Continuous drain reverse current (Note 1)	I_{DR}	—	—	—	14	A
Pulse drain reverse current (Note 1)	I_{DRP}	—	—	—	56	A
Forward voltage (diode)	V_{DSF}	$I_{DR} = 14\text{ A}$, $V_{GS} = 0\text{ V}$	—	—	-1.7	V
Reverse recovery time	t_{rr}	$I_{DR} = 14\text{ A}$, $V_{GS} = 0\text{ V}$, $dI_{DR}/dt = 100\text{ A}/\mu\text{s}$	—	1300	—	ns
Reverse recovery charge	Q_{rr}		—	18	—	μC

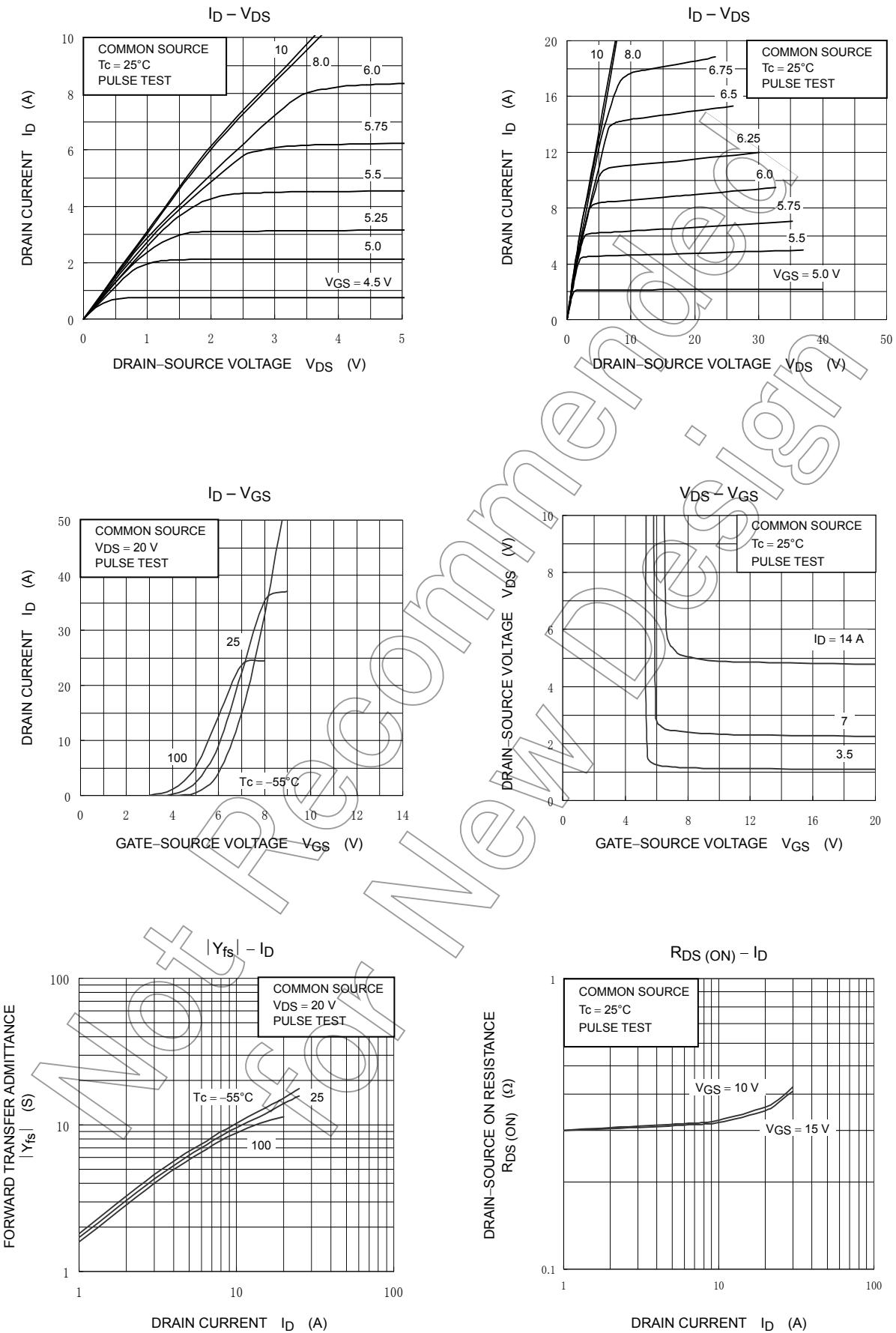
Marking

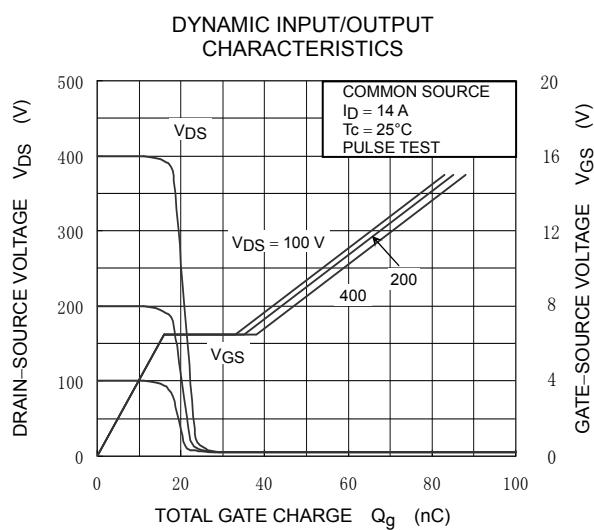
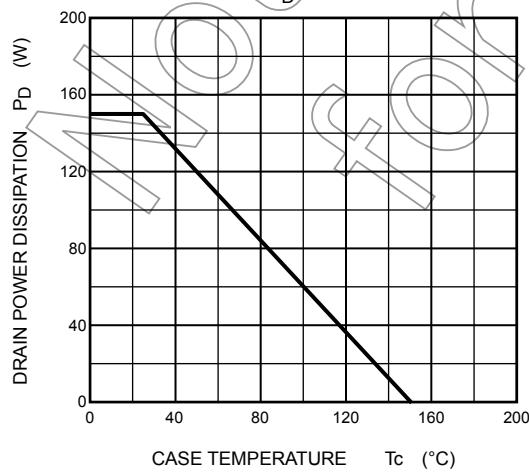
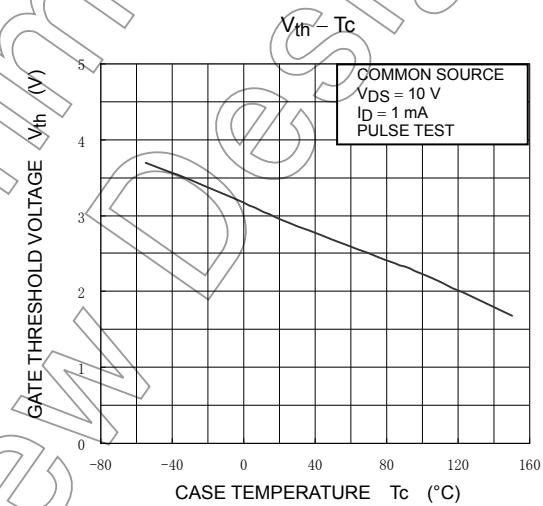
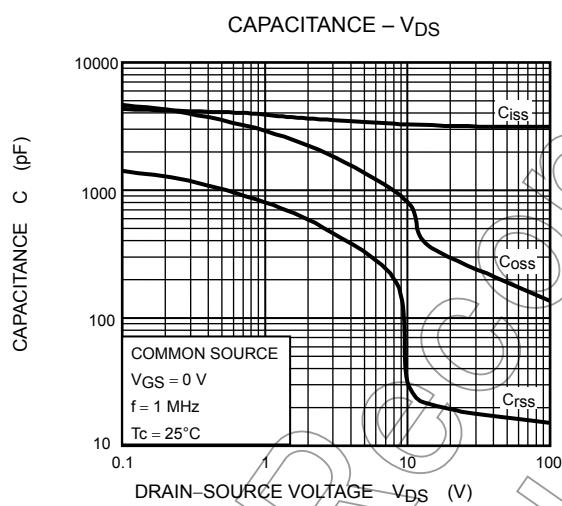
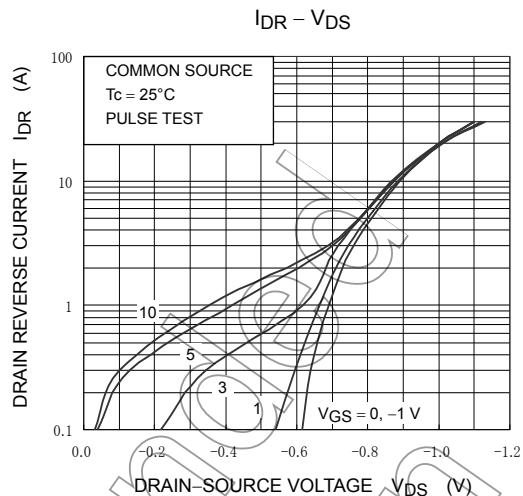
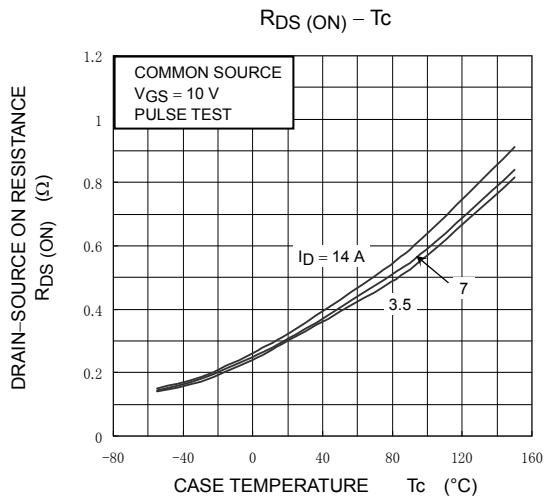


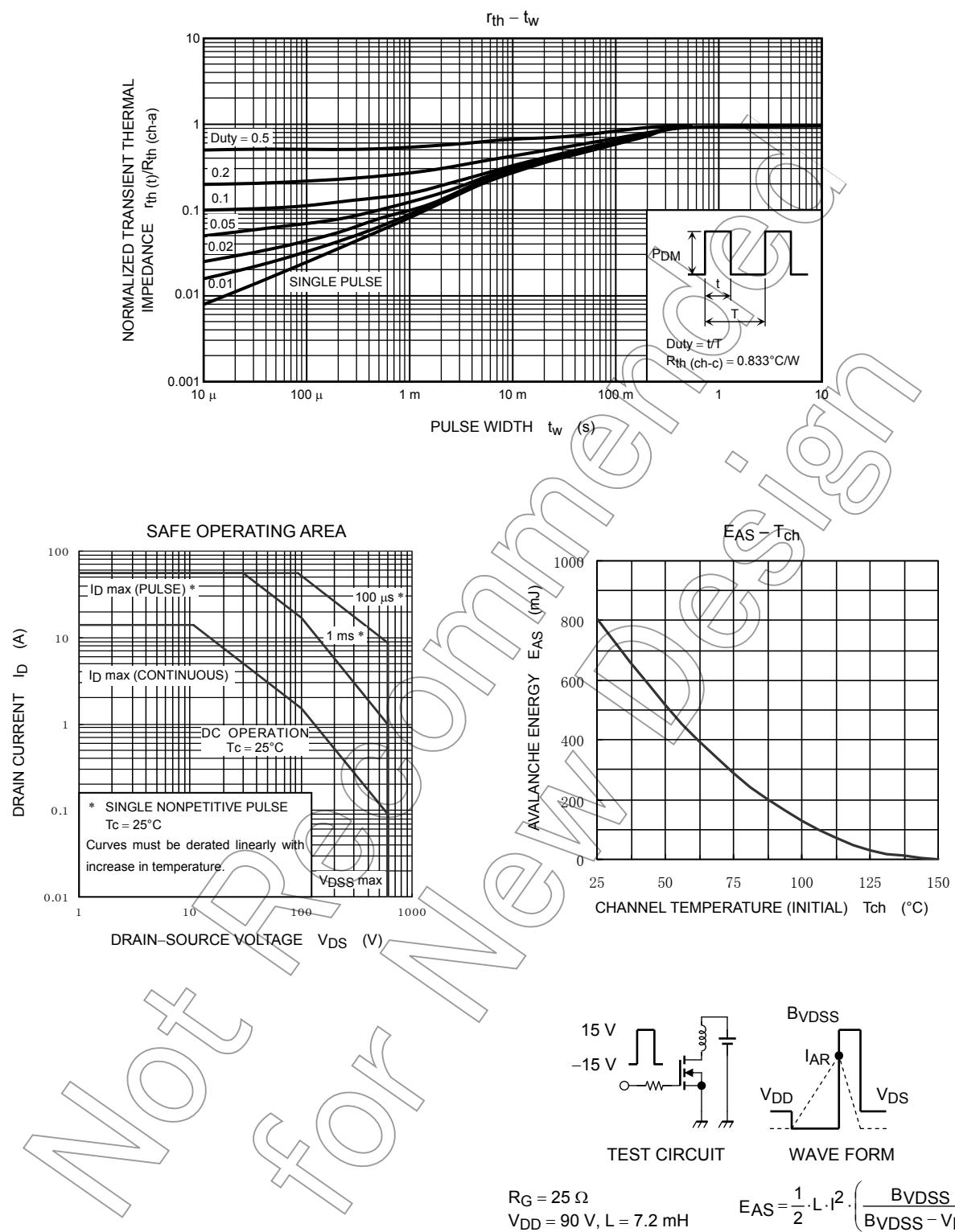
Note 4: A line under a Lot No. identifies the indication of product Labels.

[[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

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